MUR8100E is a Preferred Device

SWITCHMODE™ Power Rectifiers

Ultrafast "E" Series with High Reverse Energy Capability

... designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- 20 mjoules Avalanche Energy Guaranteed
- Excellent Protection Against Voltage Transients in Switching Inductive Load Circuits
- Ultrafast 75 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL94, V_O @ 1/8"
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Reverse Voltage to 1000 Volts

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: U880E, U8100E

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage MUR880E MUR8100E	V _{RRM} V _{RWM} V _R	800 1000	V
Average Rectified Forward Current (Rated V_R , $T_C = 150$ °C) Total Device	I _{F(AV)}	8.0	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 150°C)	I _{FM}	16	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	100	A
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +175	°C



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ULTRAFAST RECTIFIERS 8.0 AMPERES 800-1000 VOLTS





CASE 221B PLASTIC

MARKING DIAGRAM



U8x0E = Device Code x = 8 or 10

ORDERING INFORMATION

Device	Package	Shipping		
MUR8100E	TO-220	50 Units/Rail		
MUR880E	TO-220	50 Units/Rail		

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{ extsf{ heta}JC}$	2.0	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	MUR880E	MUR8100E	Unit
Maximum Instantaneous Forward Voltage (Note 1.) ($i_F = 8.0 \text{ Amps}, T_C = 150^{\circ}\text{C}$) ($i_F = 8.0 \text{ Amps}, T_C = 25^{\circ}\text{C}$)	۷F	1.5 1.8		Volts
Maximum Instantaneous Reverse Current (Note 1.) (Rated dc Voltage, $T_C = 100^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$)	i _R	500 25		μA
Maximum Reverse Recovery Time (I _F = 1.0 Amp, di/dt = 50 Amps/μs) (I _F = 0.5 Amp, i _R = 1.0 Amp, I _{REC} = 0.25 Amp)	t _{rr}	100 75		ns
Controlled Avalanche Energy (See Test Circuit in Figure 6)	W _{AVAL}	2	0	mJ

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.





Figure 6. Test Circuit

The unclamped inductive switching circuit shown in Figure 6 was used to demonstrate the controlled avalanche capability of the new "E" series Ultrafast rectifiers. A mercury switch was used instead of an electronic switch to simulate a noisy environment when the switch was being opened.

When S_1 is closed at t_0 the current in the inductor I_L ramps up linearly; and energy is stored in the coil. At t_1 the switch is opened and the voltage across the diode under test begins to rise rapidly, due to di/dt effects, when this induced voltage reaches the breakdown voltage of the diode, it is clamped at BV_{DUT} and the diode begins to conduct the full load current which now starts to decay linearly through the diode, and goes to zero at t_2 .

By solving the loop equation at the point in time when S_1 is opened; and calculating the energy that is transferred to the diode it can be shown that the total energy transferred is equal to the energy stored in the inductor plus a finite amount of energy from the V_{DD} power supply while the diode is in



Figure 7. Current-Voltage Waveforms

breakdown (from t_1 to t_2) minus any losses due to finite component resistances. Assuming the component resistive elements are small Equation (1) approximates the total energy transferred to the diode. It can be seen from this equation that if the V_{DD} voltage is low compared to the breakdown voltage of the device, the amount of energy contributed by the supply during breakdown is small and the total energy can be assumed to be nearly equal to the energy stored in the coil during the time when S₁ was closed, Equation (2).

The oscilloscope picture in Figure 8, shows the MUR8100E in this test circuit conducting a peak current of one ampere at a breakdown voltage of 1300 volts, and using Equation (2) the energy absorbed by the MUR8100E is approximately 20 mjoules.

Although it is not recommended to design for this condition, the new "E" series provides added protection against those unforeseen transient viruses that can produce unexplained random failures in unfriendly environments.



$$W_{AVAL} \approx \frac{1}{2} LI_{LPK}^{2} \left(\frac{BV_{DUT}}{BV_{DUT} - V_{DD}} \right)$$

EQUATION (2):

$$W_{AVAL} \approx \frac{1}{2} LI_{LPK}^2$$



Figure 8. Current-Voltage Waveforms







Figure 10. Typical Capacitance